S/N 10/028,643

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Kie Y. Ahn et al.

Serial No.:

10/028,643

Filed:

December 20, 2001

Title:

LOW-TEMPERATURE GROWN HIGH QUALITY ULTRA-THIN

**GATE DIELECTRICS** 

RESPONSE TO RESTRICTION REQUIREMENT

Commissioner for Patents Washington, D.C. 20231

In response to the Restriction Requirement mailed August 21, 2002, Applicant elects, without traverse, claims 1-12 and 55 drawn to a method of making a field effect transistor.

Applicant affirms that, as noted by the examiner, claim 1 is generic to the second species (claims 22-29) and the third species (claims 30-37).

The Examiner is invited to contact Applicant's Representatives at the below-listed telephone number if there are any questions regarding this Response or if prosecution of this application may be assisted thereby.

Respectfully submitted,

KIE Y. AHN ET AL.

By their Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

Examiner: Long Pham

Group Art Unit: 2823

Docket: 130\$030US

P.O. Box 2938

Minneapolis, MN 55402

(612) 373-6944

Date 9-/2-02

David C. Peterson

Reg. No. 47,857

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Commissioner of Patents, Washington, D.C. 20231, on this day of September, 2002.

Name

Amy moriarly

Signature